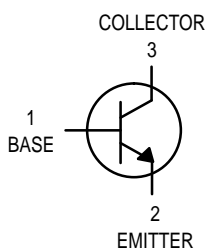


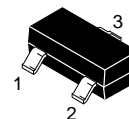
# Switching Transistors

## NPN Silicon



**MMBT2369LT1**  
**MMBT2369ALT1\***

\*Motorola Preferred Device



CASE 318-08, STYLE 6  
SOT-23 (TO-236AB)

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	15	Vdc
Collector-Emitter Voltage	$V_{CES}$	40	Vdc
Collector-Base Voltage	$V_{CBO}$	40	Vdc
Emitter-Base Voltage	$V_{EBO}$	4.5	Vdc
Collector Current — Continuous	$I_C$	200	mAdc

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board <sup>(1)</sup> $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	225 1.8	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate, <sup>(2)</sup> $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

### DEVICE MARKING

MMBT2369LT1 = M1J; MMBT2369ALT1 = 1JA

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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### OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage (3) ( $I_C = 10 \text{ mAdc}$ , $I_B = 0$ )	$V_{(BR)CEO}$	15	—	—	Vdc
Collector-Emitter Breakdown Voltage ( $I_C = 10 \mu\text{Adc}$ , $V_{BE} = 0$ )	$V_{(BR)CES}$	40	—	—	Vdc
Collector-Base Breakdown Voltage ( $I_C = 10 \mu\text{Adc}$ , $I_E = 0$ )	$V_{(BR)CBO}$	40	—	—	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 10 \mu\text{Adc}$ , $I_C = 0$ )	$V_{(BR)EBO}$	4.5	—	—	Vdc
Collector Cutoff Current ( $V_{CB} = 20 \text{ Vdc}$ , $I_E = 0$ ) ( $V_{CB} = 20 \text{ Vdc}$ , $I_E = 0$ , $T_A = 150^\circ\text{C}$ )	$I_{CBO}$	— —	— —	0.4 30	$\mu\text{Adc}$
Collector Cutoff Current ( $V_{CE} = 20 \text{ Vdc}$ , $V_{BE} = 0$ )	$I_{CES}$	—	—	0.4	$\mu\text{Adc}$

- FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.
- Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

Thermal Clad is a trademark of the Bergquist Company.

**Preferred** devices are Motorola recommended choices for future use and best overall value.

# MMBT2369LT1 MMBT2369ALT1

## ELECTRICAL CHARACTERISTICS (continued) ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit	
<b>ON CHARACTERISTICS</b>						
DC Current Gain (3) ( $I_C = 10\text{ mA}$ , $V_{CE} = 1.0\text{ Vdc}$ ) ( $I_C = 10\text{ mA}$ , $V_{CE} = 1.0\text{ Vdc}$ ) ( $I_C = 10\text{ mA}$ , $V_{CE} = 0.35\text{ Vdc}$ ) ( $I_C = 10\text{ mA}$ , $V_{CE} = 0.35\text{ Vdc}$ , $T_A = -55^\circ\text{C}$ ) ( $I_C = 30\text{ mA}$ , $V_{CE} = 0.4\text{ Vdc}$ ) ( $I_C = 100\text{ mA}$ , $V_{CE} = 2.0\text{ Vdc}$ ) ( $I_C = 100\text{ mA}$ , $V_{CE} = 1.0\text{ Vdc}$ )	MMBT2369 MMBT2369A MMBT2369A MMBT2369A MMBT2369A MMBT2369 MMBT2369A	$h_{FE}$	40 — 40 20 30 20 20	— — — — — — —	120 120 — — — — —	—
Collector–Emitter Saturation Voltage (3) ( $I_C = 10\text{ mA}$ , $I_B = 1.0\text{ mA}$ ) ( $I_C = 10\text{ mA}$ , $I_B = 1.0\text{ mA}$ ) ( $I_C = 10\text{ mA}$ , $I_B = 1.0\text{ mA}$ , $T_A = +125^\circ\text{C}$ ) ( $I_C = 30\text{ mA}$ , $I_B = 3.0\text{ mA}$ ) ( $I_C = 100\text{ mA}$ , $I_B = 10\text{ mA}$ )	MMBT2369 MMBT2369A MMBT2369A MMBT2369A MMBT2369A	$V_{CE(sat)}$	— — — — —	— — — — —	0.25 0.20 0.30 0.25 0.50	Vdc
Base–Emitter Saturation Voltage (3) ( $I_C = 10\text{ mA}$ , $I_B = 1.0\text{ mA}$ ) ( $I_C = 10\text{ mA}$ , $I_B = 1.0\text{ mA}$ , $T_A = -55^\circ\text{C}$ ) ( $I_C = 30\text{ mA}$ , $I_B = 3.0\text{ mA}$ ) ( $I_C = 100\text{ mA}$ , $I_B = 10\text{ mA}$ )	MMBT2369A MMBT2369A MMBT2369A MMBT2369A	$V_{BE(sat)}$	0.7 — — —	— — — —	0.85 1.02 1.15 1.60	Vdc
<b>SMALL–SIGNAL CHARACTERISTICS</b>						
Output Capacitance ( $V_{CB} = 5.0\text{ Vdc}$ , $I_E = 0$ , $f = 1.0\text{ MHz}$ )		$C_{obo}$	—	—	4.0	pF
Small Signal Current Gain ( $I_C = 10\text{ mA}$ , $V_{CE} = 10\text{ Vdc}$ , $f = 100\text{ MHz}$ )		$h_{fe}$	5.0	—	—	—
<b>SWITCHING CHARACTERISTICS</b>						
Storage Time ( $I_{B1} = I_{B2} = I_C = 10\text{ mA}$ )		$t_s$	—	5.0	13	ns
Turn–On Time ( $V_{CC} = 3.0\text{ Vdc}$ , $I_C = 10\text{ mA}$ , $I_{B1} = 3.0\text{ mA}$ )		$t_{on}$	—	8.0	12	ns
Turn–Off Time ( $V_{CC} = 3.0\text{ Vdc}$ , $I_C = 10\text{ mA}$ , $I_{B1} = 3.0\text{ mA}$ , $I_{B2} = 1.5\text{ mA}$ )		$t_{off}$	—	10	18	ns

3. Pulse Test: Pulse Width  $\leq 300\ \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

SWITCHING TIME EQUIVALENT TEST CIRCUITS FOR 2N2369, 2N3227

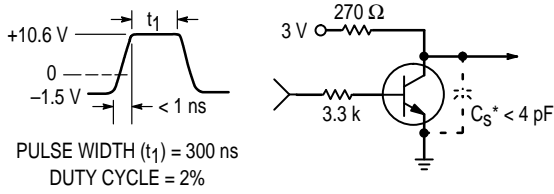


Figure 1.  $t_{on}$  Circuit — 10 mA

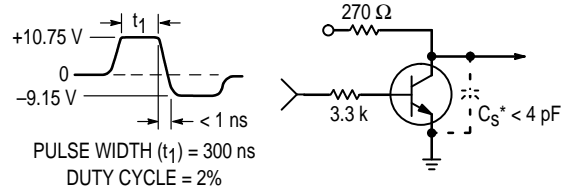


Figure 3.  $t_{off}$  Circuit — 10 mA

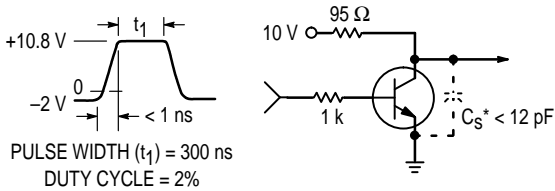


Figure 2.  $t_{on}$  Circuit — 100 mA

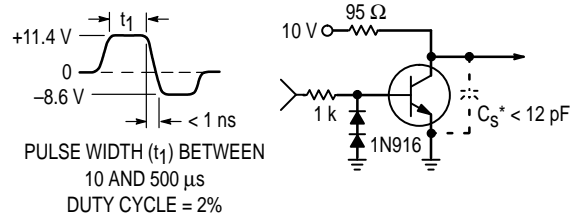


Figure 4.  $t_{off}$  Circuit — 100 mA

\* Total shunt capacitance of test jig and connectors.

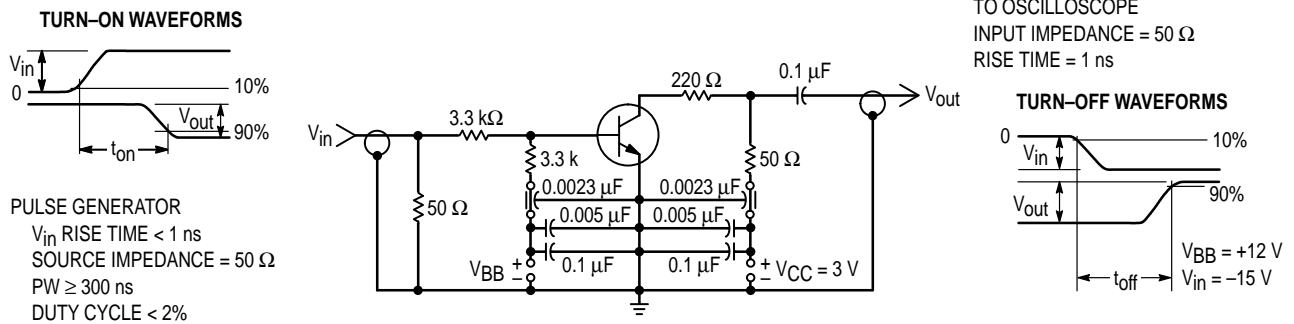


Figure 5. Turn-On and Turn-Off Time Test Circuit

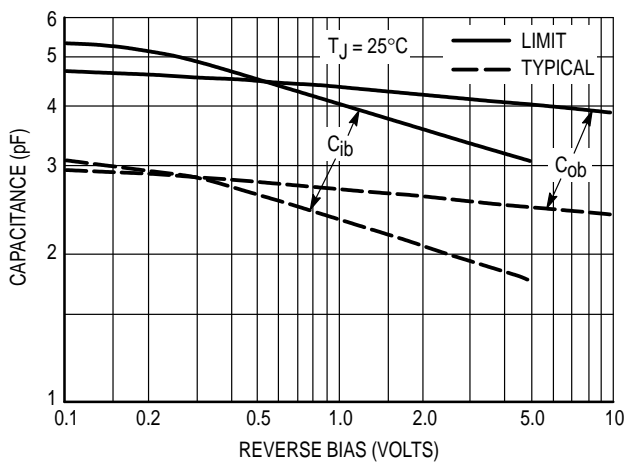


Figure 6. Junction Capacitance Variations

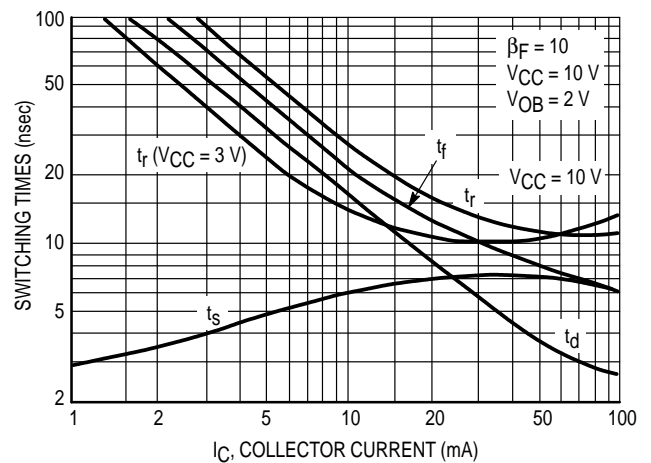
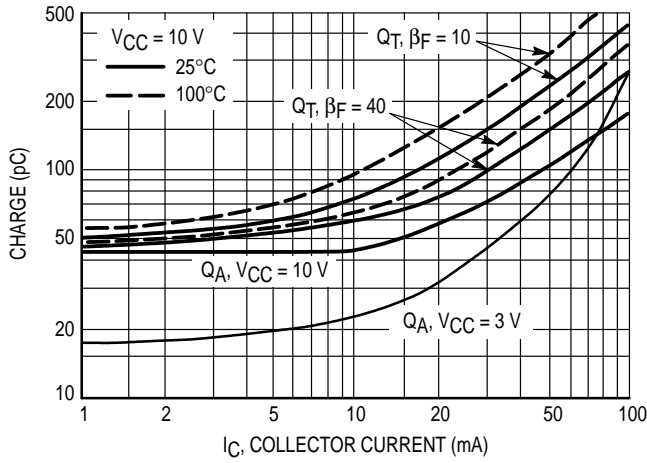
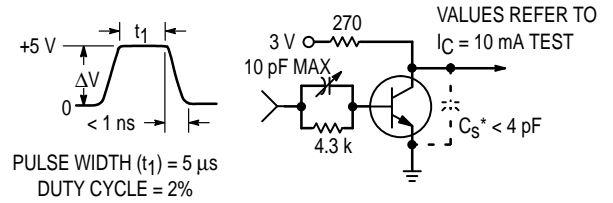


Figure 7. Typical Switching Times

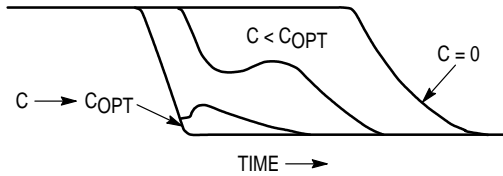
**MMBT2369LT1 MMBT2369ALT1**



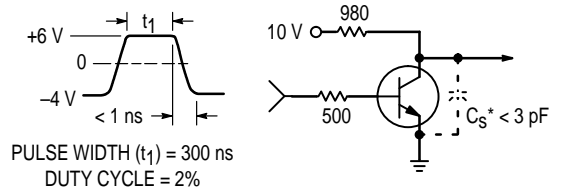
**Figure 8. Maximum Charge Data**



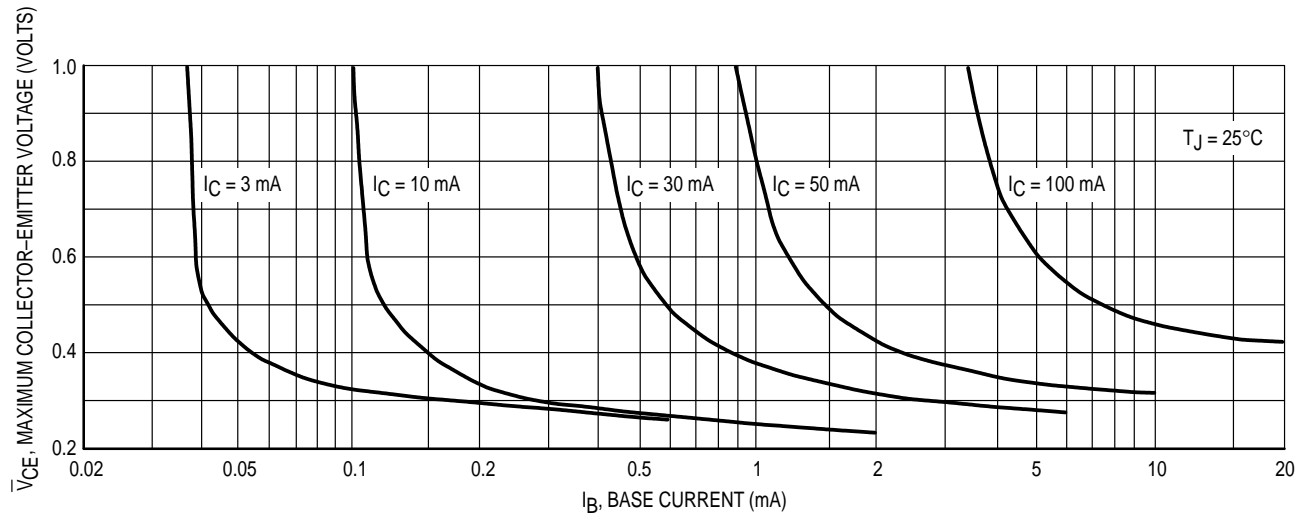
**Figure 9. Q<sub>T</sub> Test Circuit**



**Figure 10. Turn-Off Waveform**



**Figure 11. Storage Time Equivalent Test Circuit**



**Figure 12. Maximum Collector Saturation Voltage Characteristics**

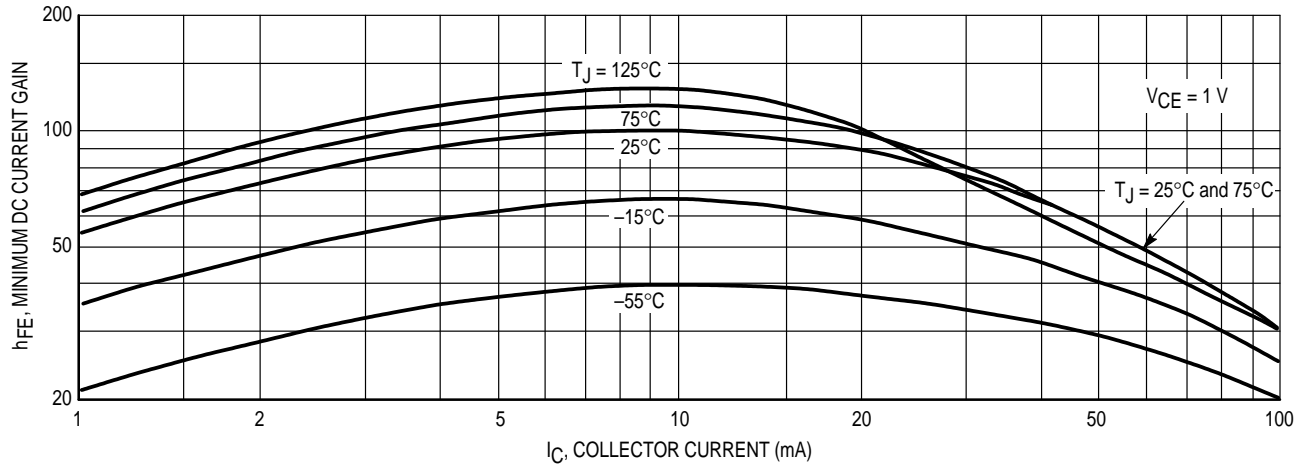


Figure 13. Minimum Current Gain Characteristics

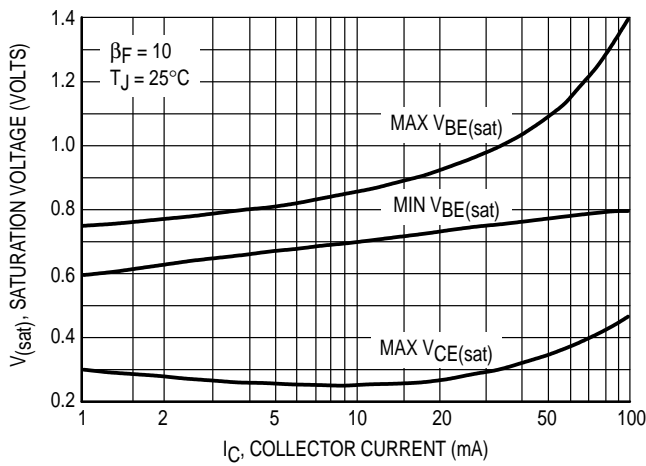


Figure 14. Saturation Voltage Limits

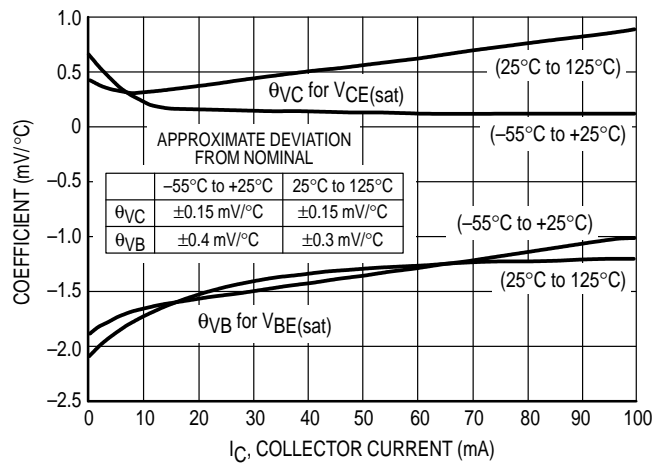


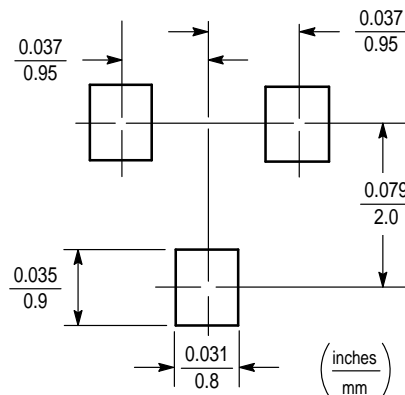
Figure 15. Typical Temperature Coefficients

INFORMATION FOR USING THE SOT-23 SURFACE MOUNT PACKAGE

MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



SOT-23

SOT-23 POWER DISSIPATION

The power dissipation of the SOT-23 is a function of the pad size. This can vary from the minimum pad size for soldering to a pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by  $T_{J(max)}$ , the maximum rated junction temperature of the die,  $R_{\theta JA}$ , the thermal resistance from the device junction to ambient, and the operating temperature,  $T_A$ . Using the values provided on the data sheet for the SOT-23 package,  $P_D$  can be calculated as follows:

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta JA}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values into the equation for an ambient temperature  $T_A$  of 25°C, one can calculate the power dissipation of the device which in this case is 225 milliwatts.

$$P_D = \frac{150^\circ\text{C} - 25^\circ\text{C}}{556^\circ\text{C/W}} = 225 \text{ milliwatts}$$

The 556°C/W for the SOT-23 package assumes the use of the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 225 milliwatts. There are other alternatives to achieving higher power dissipation from the SOT-23 package. Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal Clad™. Using a board material such as Thermal Clad, an aluminum core board, the power dissipation can be doubled using the same footprint.

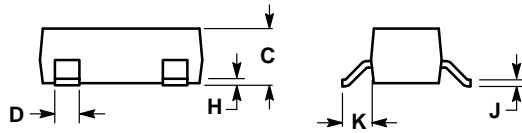
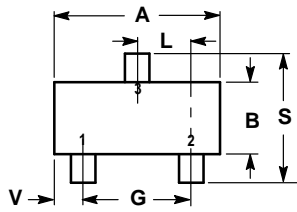
SOLDERING PRECAUTIONS

The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.\*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference shall be a maximum of 10°C.
- The soldering temperature and time shall not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient shall be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes. Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling.

\* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.

PACKAGE DIMENSIONS



NOTES:


1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0180	0.0236	0.45	0.60
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.0984	2.10	2.50
V	0.0177	0.0236	0.45	0.60

STYLE 6:

- PIN 1. BASE
2. EMITTER
3. COLLECTOR

**CASE 318-08  
SOT-23 (TO-236AB)  
ISSUE AE**

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